

Giant parallel and perpendicular exchange biases in MnPd/Co bilayers

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Abstract: A systematic study of exchange bias in MnPd/Co bilayers has been carried out in both parallel and perpendicular directions, where the dependences of blocking temperature, exchange bias and unidirectional anisotropy constant on the thicknesses of MnPd and Co layers were investigated. One of the particular interests is that the blocking temperature of parallel exchange bias is higher than that of perpendicular exchange bias which can be interpreted as the difference of the ordering in parallel and perpendicular direction. The other is that a huge unidirectional anisotropy constant, $J_K = 5.5 \text{ erg/cm}^2$ was observed, which is in reasonable agreement with the theoretical prediction based on the model by Meiklejohn and Bean. ?? 2007 WILEY-VCH Verlag GmbH & Co. KGaA.,

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References:

1. Meiklejohn, W.H., Bean, C.P., (1956) Phys. Rev, 102, p. 1413
2. Nogu??s, J., Schuller, I.K., (1999) J. Magn. Magn. Mater, 192, p. 203
3. Mauri, D., Siegmann, H.C., Bagus, P.S., Kay, E., (1987) J. Appl. Phys, 62, p. 3047
4. Malozemoff, A.P., (1988) Phys. Rev. B, 37, p. 7673
5. Koon, N.C., (1997) Phys. Rev. Lett, 78, p. 4865
6. Imakita, I., Tsunoda, M., Takahashi, M., (2004) Appl. Phys. Lett, 85, p. 3812
7. Tsunoda, M., (2006) Appl. Phys. Lett, 89, p. 172501
8. Thuy, N.P., (2006) J. Magn. Magn. Mater, 192, p. 203
9. Nam, N.T., (2007) J. Magn. Magn. Mater, , accepted
10. N. N. Phuoc and T. Suzuki, J. Appl. Phys. 99, 08C107 (2006)N. N. Phuoc and T. Suzuki, J. Appl. Phys. 101, 009E51 (2007)Phuoc, N.N., Suzuki, T., (2006) IEEE Trans. Magn, 42, p. 2996
11. Farrow, R.F.C., (1997) J. Appl. Phys, 81, p. 4986
12. Tang, Y.J., (2000) Phys. Rev. B, 62, p. 8654
13. Seu, K.A., (2003) J. Appl. Phys, 93, p. 6611
14. van der Zaag, P.J., (1996) J. Appl. Phys, 79, p. 5103